
IRFZ48N Inverter

What is irfz48n?

INCHANGE Semiconductor isc Product Specification isc N-Channel MOSFET Transistor
IRFZ48N FEATURES Drain Current ID= 64A@ TC=25 Drain Source Voltage- VDSS= 55V
(Min) Static Drain-Source On-Resistance RDS (on) = 0.014 (Max) Fast Switching
DESCRIPTION Designed for use in switch mode power supplies and general purpose applications.

What are the irfz48n MOSFET specs?

IRFZ48N MOSFET specs: N-Ch/55V/64A. View the complete datasheet,pin configuration,and find equivalent or replacement transistors.

What is irfz48n trenchmostm transistor?

Philips Semiconductors Product specification N-channel enhancement modeIRFZ48N
TrenchMOSTM transistor GENERAL DESCRIPTION QUICK REFERENCE DATA N-channel
enhancement mode SYMBOL PARAMETER MAX. UNIT standard level field-effect power
transistor in a plastic envelope using VDS Drain-source voltage 55 V trench technology.

What happened to International Rectifier?

In 2014,IR was acquired by Infineon Technologies,a leading provider of power management and control products and other semiconductor solutions. The International Rectifier brand is no longer in use,but its technology and products continue to be a part of Infineon's portfolio.

Description Advanced HEXFET® Power MOSFETs from International Rectifier utilize advanced processing techniques to achieve extremely low on-resistance per silicon ...

IRFZ48N MOSFET PDF specs: N-Ch/55V/64A. View the complete specification, pin configuration and find equivalents or replacement ...

Part #: IRFZ48N. Download. File Size: 443Kbytes. Page: 4 Pages. Description: N-Ch 60V Fast Switching MOSFETs. Manufacturer: EVER SEMICONDUCTOR CO.,LIMITED.

Irfz48n N-Channel Mosfet - 55V, 60A, Suitable for Switching Regulators and Inverters, Find Details and Price about Irfz48n N-Channel Power Mosfet from Irfz48n N ...

IRFZ48N is an Discrete semiconductor;The transistor manufactured by International Rectifier Infineon . Download the IRFZ48N datasheet to learn more about specifications, pins, ...

The TO-220 package is universally preferred for all commercial-industrial applications at power dissipation levels to approximately 50 watts. The low thermal resistance ...

Description Advanced HEXFET®Power MOSFETs from International Rectifier utilize advanced processing techniques to achieve extremely low on-resistance per silicon area. This benefit, ...

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